## AM4533C

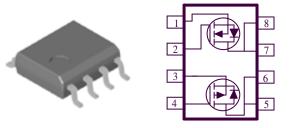
## **Analog Power**

# P & N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$	
20	$40 @ V_{GS} = 2.5V$	6.0	
20	$31 @ V_{GS} = 4.5V$	6.9	
-20	$80 @ V_{GS} = -2.5V$	-4.2	
	$52 @ V_{GS} = -4.5V$	-5.2	



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25$ °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	N-Channel	P-Channel	Units	
Drain-Source Voltage		V <sub>DS</sub>	20	-20	v	
Gate-Source Voltage		V <sub>GS</sub> ±8		±8	V	
Continues Durin Courset <sup>a</sup>	T <sub>A</sub> =25°C	I <sub>D</sub>	6.9	-5.2		
Continuous Drain Current <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$		5.4	-6.8	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	20	-20		
Continuous Source Current (Diode Conduction) <sup>a</sup>		Is	1.3	-1.3	Α	
Damon Discinction <sup>a</sup>	T <sub>A</sub> =25°C	P.,	2.1	2.1	W	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	I D	1.3	1.3		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	$R_{\theta JA}$	62.5	°C/W		
	Steady-State		110	°C/W		

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

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SI LEHITERITONS (IA		LESS OTHERWISE NO					
Parameter	Symbol	Test Conditions	Limits				Unit
			Ch	Min	Тур	Max	
Static							
Gate-Threshold Voltage	V <sub>GS(th)</sub>	VGS = VDS, $ID = 250  uA$	Ν	0.4			v
	(U3(tii)	$V_{GS} = V_{DS}$ , $I_D = -250 \text{ uA}$	Р	-0.4			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{GS} = -8 V, V_{DS} = 0 V$	Р			±100	nA
, , ,	000	$V_{GS} = 8 V, V_{DS} = 0 V$	N			±100	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = -16 V, V_{GS} = 0 V$	Р			-1	uA
		$V_{DS} = 16 \text{ V}, V_{GS} = 0 \text{ V}$	N			1	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 4.5 V$	N	20			Α
		$V_{DS} = -5 V, V_{GS} = -4.5 V$	Р	-20		21	
	-	VGS = 4.5 V, ID = 6.9 A	Ν			31	mΩ
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	VGS = 2.5 V, ID = 6 A				40	
		VGS = -4.5 V, ID = -5.2 A	Р			52	
		VGS = -2.5 V, ID = -4.2 A	N		25	80	
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 6.9 \text{ A}$	N		25		s
		$V_{DS} = -15 \text{ V}, I_D = -5.2 \text{ A}$	Р		10		
Dynamic			1			1	
Total Gate Charge	Q <sub>g</sub>	$\begin{array}{c} Q_{g} \\ Q_{gs} \\ Q_{gs} \end{array} \begin{array}{c} N-Channel \\ V_{DS}=15V, V_{GS}=4.5V, I_{D}=6.9A \\ P-Channel \\ V_{DS}=-15V, V_{GS}=-4.5V, I_{D}=-5.2A \end{array}$	N		6.0	-	nC
6	-0		Р		25		
Gate-Source Charge	$Q_{gs}$		N		1.0		
			P		2.4		
Gate-Drain Charge	$Q_{gd}$		N P		1.5		
			P N		3.9 7.4		
Turn-On Delay Time	$t_{d(on)}$	N-Chaneel $V_{DD}$ =15V, VGS=4.5V, ID=1A , $R_{GEN}$ =6 $\Omega$ , P-Channel	P N		7.6		nS
			P N		4	1	
Rise Time	t <sub>r</sub>		P		6.8	1	
Turn-Off Delay Time			N		22.2		
	$t_{d(off)}$		P		33.6	1	
		RGEN= $6\Omega$	N		3.6	1	
Fall-Time	t <sub>f</sub>	t <sub>f</sub>	P		23.2	1	

Notes

a. Pulse test:  $PW \le 300$  us duty cycle  $\le 2\%$ .

b. Guaranteed by design, not subject to production testing.

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